

S-1212B/D Series

HIGH-WITHSTAND VOLTAGE LOW CURRENT CONSUMPTION LOW DROPOUT CMOS VOLTAGE REGULATOR

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Rev.3.0 00

The S-1212B/D Series, developed by using high-withstand voltage CMOS process technology, is a positive voltage regulator with a high-withstand voltage, low current consumption and high-accuracy output voltage, and has a built-in ON / OFF circuit.

The S-1212B/D Series operates at the maximum operation voltage of 36 V and a low current consumption of 6.5 μ A typ., and has a built-in low on-resistance output transistor which provides a very small dropout voltage and a large output current. Also, a built-in overcurrent protection circuit to limit overcurrent of the output transistor and a built-in thermal shutdown circuit to limit heat are included.

■ Features

• Output voltage: 2.5 V to 16.0 V, selectable in 0.1 V step

Input voltage: 3.0 V to 36 V
 Output voltage accuracy: ±2.0% (Ta = +25°C)

• Current consumption: During operation: 6.5 μ A typ. (Ta = +25°C)

During power-off: 0.1 μ A typ. (Ta = +25°C)

Output current: Possible to output 250 mA (at V_{IN} ≥ V_{OUT(S)} + 2.0 V)^{*1}
 Input capacitor: A ceramic capacitor can be used. (1.0 μF or more)
 Output capacitor: A ceramic capacitor can be used. (1.0 μF to 100 μF)

Built-in overcurrent protection circuit: Limits overcurrent of output transistor.
 Built-in thermal shutdown circuit: Detection temperature 165°C typ.

• Built-in ON / OFF circuit: Ensures long battery life.

• Built-in discharge shunt circuit: Discharges the electric charge of the output capacitor during power-off.

 $(R_{LOW} = 70 \text{ k}\Omega \text{ typ.})$

• Operation temperature range: Ta = -40°C to +105°C

• Lead-free (Sn 100%), halogen-free

■ Applications

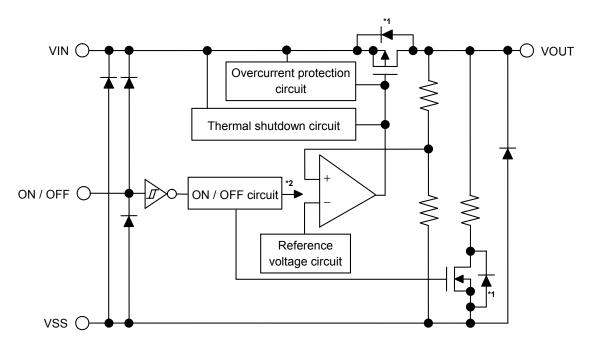
- Constant-voltage power supply for industrial equipment
- Constant-voltage power supply for home electric appliance

■ Packages

- TO-252-5S(A)
- HSOP-8A
- HSOP-6
- SOT-89-5
- HTMSOP-8
- SOT-23-5

^{*1.} Please make sure that the loss of the IC will not exceed the power dissipation when the output current is large.

■ Block Diagram



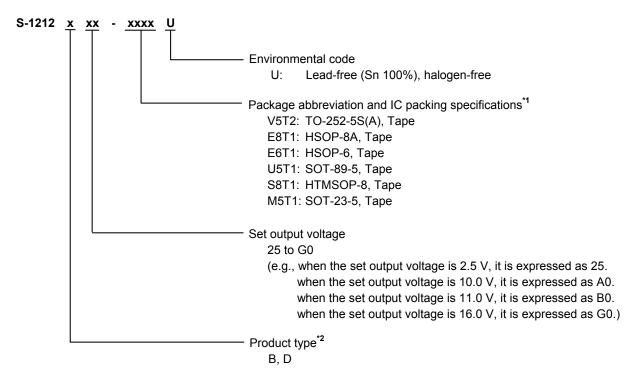
- *1. Parasitic diode
- *2. The ON / OFF circuit controls the internal circuit and the output transistor.

Figure 1

■ Product Name Structure

Users can select the output voltage and package type for the S-1212B/D Series. Refer to "1. Product name" regarding the contents of product name, "2. Function list of product types" regarding the product type, "3. Packages" regarding the package drawings and "4. Product name list" for details of product names.

1. Product name



- *1. Refer to the tape drawing.
- *2. Refer to "2. Function list of product types" and "3. ON / OFF pin" in "■ Operation".

2. Function list of product types

Table 1

| Product Type | ON / OFF Logic | ON / OFF Pin Input Voltage "H" | ON / OFF Pin Input Voltage "L" |
|--------------|----------------|--------------------------------|--------------------------------|
| В | Active "H" | 1.5 V min. | 0.25 V max. |
| D | Active "H" | 2.0 V min. | 0.8 V max. |

3. Packages

Table 2 Package Drawing Codes

| Package Name | Dimension | Tape | Reel | Land |
|--------------|--------------|--------------|--------------|--------------|
| TO-252-5S(A) | VA005-A-P-SD | VA005-A-C-SD | VA005-A-R-SD | VA005-A-L-SD |
| HSOP-8A | FH008-A-P-SD | FH008-A-C-SD | FH008-A-R-SD | FH008-A-L-SD |
| HSOP-6 | FH006-A-P-SD | FH006-A-C-SD | FH006-A-R-S1 | _ |
| SOT-89-5 | UP005-A-P-SD | UP005-A-C-SD | UP005-A-R-SD | _ |
| HTMSOP-8 | FP008-A-P-SD | FP008-A-C-SD | FP008-A-R-SD | FP008-A-L-SD |
| SOT-23-5 | MP005-A-P-SD | MP005-A-C-SD | MP005-A-R-SD | _ |

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4. Product name list

4. 1 S-1212B/D Series B type

ON / OFF logic: Active "H"

ON / OFF pin input voltage "H" (V_{SH}) = 1.5 V min., ON / OFF pin input voltage "L" (V_{SL}) = 0.25 V max.

.

Table 3

| Output Voltage | TO-252-5S(A) | HSOP-8A | HSOP-6 | SOT-89-5 | HTMSOP-8 | SOT-23-5 |
|---------------------|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|
| $3.3~V \pm 2.0\%$ | S-1212B33-V5T2U | S-1212B33-E8T1U | S-1212B33-E6T1U | S-1212B33-U5T1U | S-1212B33-S8T1U | S-1212B33-M5T1U |
| 5.0 V ± 2.0% | S-1212B50-V5T2U | S-1212B50-E8T1U | S-1212B50-E6T1U | S-1212B50-U5T1U | S-1212B50-S8T1U | S-1212B50-M5T1U |
| $8.0 \ V \pm 2.0\%$ | S-1212B80-V5T2U | S-1212B80-E8T1U | S-1212B80-E6T1U | S-1212B80-U5T1U | S-1212B80-S8T1U | S-1212B80-M5T1U |
| 12.0 V ± 2.0% | S-1212BC0-V5T2U | S-1212BC0-E8T1U | S-1212BC0-E6T1U | S-1212BC0-U5T1U | S-1212BC0-S8T1U | S-1212BC0-M5T1U |

Remark Please contact our sales office for products with specifications other than the above output voltage.

4. 2 S-1212B/D Series D type

ON / OFF logic: Active "H"

ON / OFF pin input voltage "H" (V_{SH}) = 2.0 V min., ON / OFF pin input voltage "L" (V_{SL}) = 0.8 V max.

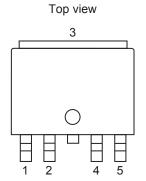
Table 4

| Output Voltage | TO-252-5S(A) | HSOP-8A | HSOP-6 | SOT-89-5 | HTMSOP-8 | SOT-23-5 |
|--------------------------|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|
| $3.3~V \pm 2.0\%$ | S-1212D33-V5T2U | S-1212D33-E8T1U | S-1212D33-E6T1U | S-1212D33-U5T1U | S-1212D33-S8T1U | S-1212D33-M5T1U |
| $5.0~V \pm 2.0\%$ | S-1212D50-V5T2U | S-1212D50-E8T1U | S-1212D50-E6T1U | S-1212D50-U5T1U | S-1212D50-S8T1U | S-1212D50-M5T1U |
| $8.0~\textrm{V}\pm2.0\%$ | S-1212D80-V5T2U | S-1212D80-E8T1U | S-1212D80-E6T1U | S-1212D80-U5T1U | S-1212D80-S8T1U | S-1212D80-M5T1U |
| 12.0 V ± 2.0% | S-1212DC0-V5T2U | S-1212DC0-E8T1U | S-1212DC0-E6T1U | S-1212DC0-U5T1U | S-1212DC0-S8T1U | S-1212DC0-M5T1U |

Remark Please contact our sales office for products with specifications other than the above output voltage.

■ Pin Configurations

1. TO-252-5S(A)



| Table 5 | | | | | | |
|---------|------------------|--------------------|--|--|--|--|
| Pin No. | Symbol | Description | | | | |
| 1 | VOUT | Output voltage pin | | | | |
| 2 | ON / OFF | ON / OFF pin | | | | |
| 3 | VSS | GND pin | | | | |
| 4 | NC ^{*1} | No connection | | | | |
| 5 | VIN | Input voltage pin | | | | |

Figure 2

***1.** The NC pin is electrically open.

The NC pin can be connected to the VIN pin or the VSS pin.

2. HSOP-8A

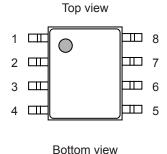


Table 6

| Pin No. | Symbol | Description |
|---------|------------------|--------------------|
| 1 | VOUT | Output voltage pin |
| 2 | NC ^{*2} | No connection |
| 3 | NC ^{*2} | No connection |
| 4 | ON / OFF | ON / OFF pin |
| 5 | VSS | GND pin |
| 6 | NC ^{*2} | No connection |
| 7 | NC ^{*2} | No connection |
| 8 | VIN | Input voltage pin |

Figure 3

- ***1.** Connect the heat sink of backside at shadowed area to the board, and set electric potential GND. However, do not use it as the function of electrode.
- ***2.** The NC pin is electrically open.

 The NC pin can be connected to the VIN pin or the VSS pin.

3. HSOP-6

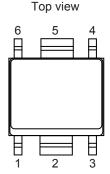


Table 7 Symbol Pin No. Description **VOUT** 1 Output voltage pin 2 VSS GND pin 3 ON / OFF ON / OFF pin NC*1 4 No connection 5 VSS GND pin 6 VIN Input voltage pin

Figure 4

***1.** The NC pin is electrically open.

The NC pin can be connected to the VIN pin or the VSS pin.

4. SOT-89-5

Top view

5
4
1
2
3

Figure 5

Table 8

| Pin No. | Symbol | Description |
|---------|------------------|--------------------|
| 1 | NC ^{*1} | No connection |
| 2 | VSS | GND pin |
| 3 | VIN | Input voltage pin |
| 4 | VOUT | Output voltage pin |
| 5 | ON / OFF | ON / OFF pin |

***1.** The NC pin is electrically open. The NC pin can be connected to the VIN pin or the VSS pin.

5. HTMSOP-8

Top view

Table 9

| Pin No. | Symbol | Description |
|---------|------------------|--------------------|
| 1 | VOUT | Output voltage pin |
| 2 | NC ^{*2} | No connection |
| 3 | NC ^{*2} | No connection |
| 4 | ON / OFF | ON / OFF pin |
| 5 | VSS | GND pin |
| 6 | NC ^{*2} | No connection |
| 7 | NC ^{*2} | No connection |
| 8 | VIN | Input voltage pin |

Figure 6

- ***1.** Connect the heat sink of backside at shadowed area to the board, and set electric potential GND. However, do not use it as the function of electrode.
- *2. The NC pin is electrically open.

The NC pin can be connected to the VIN pin or the VSS pin.

6. SOT-23-5

Top view



Figure 7

Table 10

| Pin No. | Symbol | Description |
|---------|------------------|--------------------|
| 1 | VIN | Input voltage pin |
| 2 | VSS | GND pin |
| 3 | NC ^{*1} | No connection |
| 4 | ON / OFF | ON / OFF pin |
| 5 | VOUT | Output voltage pin |

^{*1.} The NC pin is electrically open.

The NC pin can be connected to the VIN pin or the VSS pin.

■ Absolute Maximum Ratings

Table 11

(Ta = +25°C unless otherwise specified)

| Item | Symbol | Absolute Maximum Rating | Unit |
|--|-----------------------|---|------|
| $V_{\rm IN}$ $V_{\rm SS} - 0.3$ to $V_{\rm SS} + 45$ | | V_{SS} – 0.3 to V_{SS} + 45 | V |
| Input voltage | V _{ON / OFF} | $V_{SS}-0.3$ to $V_{IN}+0.3 \le V_{SS}+45$ | V |
| Output voltage | V _{OUT} | $V_{SS} - 0.3$ to $V_{IN} + 0.3 \leq V_{SS} + 45$ | V |
| Output current | I _{OUT} | 280 | mA |
| Junction temperature | Tj | -40 to +150 | °C |
| Operation ambient temperature | T _{opr} | -40 to +105 | °C |
| Storage temperature | T _{stg} | -40 to +150 | °C |

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

■ Thermal Resistance Value

Table 12

| Item | Symbol | Cond | dition | Min. | Тур. | Max. | Unit |
|--|---------------|--------------|---------|------|------|------|------|
| | | | Board A | _ | 90 | - | °C/W |
| | | | Board B | - | 58 | _ | °C/W |
| | | TO-252-5S(A) | Board C | 1 | 38 | 1 | °C/W |
| | | | Board D | 1 | 30 | I | °C/W |
| | | | Board E | - | 29 | _ | °C/W |
| | | | Board A | _ | 115 | _ | °C/W |
| | | | Board B | _ | 82 | _ | °C/W |
| | | HSOP-8A | Board C | _ | 42 | _ | °C/W |
| | | | Board D | - | 43 | _ | °C/W |
| | | | Board E | - | 35 | _ | °C/W |
| | | | Board A | - | 106 | _ | °C/W |
| | | HSOP-6 | Board B | _ | 82 | _ | °C/W |
| | | | Board C | _ | _ | _ | °C/W |
| | | | Board D | _ | 51 | _ | °C/W |
| Junction-to-ambient thermal resistance*1 | | | Board E | _ | 48 | _ | °C/W |
| Junction-to-ambient thermal resistance | θ_{ja} | | Board A | _ | 123 | _ | °C/W |
| | | | Board B | _ | 90 | _ | °C/W |
| | | SOT-89-5 | Board C | _ | _ | _ | °C/W |
| | | | Board D | _ | 53 | _ | °C/W |
| | | | Board E | _ | 41 | _ | °C/W |
| | | | Board A | _ | 161 | _ | °C/W |
| | | | Board B | _ | 116 | _ | °C/W |
| | | HTMSOP-8 | Board C | _ | 44 | _ | °C/W |
| | | | Board D | _ | 44 | - | °C/W |
| | | | Board E | _ | 35 | - | °C/W |
| | | | Board A | _ | 180 | - | °C/W |
| | | | Board B | _ | 143 | - | °C/W |
| | | SOT-23-5 | Board C | 1 | _ | _ | °C/W |
| | | | Board D | _ | 1 | _ | °C/W |
| | | | Board E | _ | 1 | ı | °C/W |

^{*1.} Test environment: compliance with JEDEC STANDARD JESD51-2A

Remark Refer to "■ **Power Dissipation**" and "**Test Board**" for details.

■ Electrical Characteristics

Table 13

(Ta = +25°C unless otherwise specified)

| Item | Symbol | Condi | ion | Min. | Тур. | Max. | Unit | Test Circuit |
|---|---|---|--|------------------|------|--------------------------------|------|-----------------|
| Output voltage*1 | $V_{\text{OUT(E)}}$ | $V_{IN} = V_{OUT(S)} + 2.0 \text{ V}, I_{OUT} = 10 \text{ m/s}$ | $I_{IN} = V_{OUT(S)} + 2.0 \text{ V}, I_{OUT} = 10 \text{ mA}$ | | | V _{OUT(S)} × 1.020 | V | 1 |
| Output current*2 | lout | $V_{IN} \ge V_{OUT(S)} + 2.0 \text{ V}$ | | × 0.980 250*4 | - | - | mA | 3 |
| Dropout voltage*3 | V _{drop} | I _{OUT} = 125 mA | | _ | 0.35 | _ | V | 1 |
| Diopout voltage | · | I _{OUT} = 250 mA | | _ | 0.80 | _ | V | 1 |
| Line regulation | $\frac{\Delta V_{OUT1}}{\Delta V_{IN} \bullet V_{OUT}}$ | $ \begin{array}{l} V_{OUT(S)} + 0.5 \ V \leq V_{IN} \leq 36 \ V, \ I_{OUT} = \\ T_j = +25 ^{\circ} C \end{array} $ | = 10 mA, | _ | 0.01 | 0.03 | %/V | 1 |
| | | $T_j = +25^{\circ}C$ | $5 \text{ V} \le V_{\text{OUT(S)}} < 5.1 \text{ V}, 0.1 \text{ mA} \le I_{\text{OUT}} \le 40 \text{ mA},$ = +25°C | | 16 | 30 | mV | 1 |
| Load regulation | ΔV_{OUT2} | $V_{IN} = V_{OUT(S)} + 2.0 \text{ V},$ 5.1 V $\leq V_{OUT(S)} < 12.1 \text{ V}, 0.1 \text{ mA} \leq$ $T_j = +25^{\circ}\text{C}$ | S I _{OUT} ≤ 40 mA, | _ | 16 | 35 | mV | 1 |
| | | $V_{IN} = V_{OUT(S)} + 2.0 \text{ V},$ $12.1 \text{ V} \le V_{OUT(S)} \le 16.0 \text{ V}, 0.1 \text{ mA}$ $T_j = +25^{\circ}\text{C}$ | \leq I _{OUT} \leq 40 mA, | - | 16 | 40 | mV | 1 |
| Current consumption during operation | I _{SS1} | V_{IN} = 18.0 V, $V_{ON/OFF}$ = V_{IN} , I_{OUT} = 0.01 mA | = 18.0 V, _{N/OFF} = V _{IN} , I _{OUT} = 0.01 mA | | 6.5 | 8.5 | μΑ | 2 |
| Current consumption during power-off | I _{SS2} | IN = 18.0 V, ON/OFF = 0 V, no load | | - | 0.1 | 3.5 | μΑ | 2 |
| Input voltage | V _{IN} | - | | 3.0 | - | 36 | V | _ |
| ON / OFF pin | V_{SH} | $V_{IN} = 18.0 \text{ V}, R_L = 1.0 \text{ k}\Omega,$ | B type (ON / OFF logic active "H") | 1.5 | Ι | _ | ٧ | 4 |
| input voltage "H" | VSH | determined by V _{OUT} output level | D type (ON / OFF logic active "H") | 2.0 | - | - | V | 4 |
| ON / OFF pin | V_{SL} | $V_{IN} = 18.0 \text{ V}, R_L = 1.0 \text{ k}\Omega,$ | B type (ON / OFF logic active "H") | - | - | 0.25 | V | 4 |
| input voltage "L" | V SL | determined by V _{OUT} output level | D type (ON / OFF logic active "H") | - | - | 0.8 | V | 4 |
| ON / OFF pin input current "H" | I _{SH} | V _{IN} = 18.0 V, V _{ON / OFF} = V _{IN} | | -0.1 | - | 0.1 | μΑ | 4 |
| ON / OFF pin input current "L" | I _{SL} | V _{IN} = 18.0 V, V _{ON / OFF} = 0 V | | -0.1 | ı | 0.1 | μΑ | 4 |
| | | | $2.5 \text{ V} \le V_{OUT(S)} < 3.6 \text{ V}$ | _ | 45 | _ | dB | 5 |
| | | $V_{IN} = V_{OUT(S)} + 2.0 \text{ V},$ f = 100 Hz, | 3.6 V ≤ V _{OUT(S)} < 6.1 V | - | 40 | - | dB | 5 |
| Ripple rejection | RR | $\Delta V_{\text{rip}} = 0.5 \text{ Vrms},$ $I_{\text{OUT}} = 10 \text{ mA}$ | 6.1 V ≤ V _{OUT(S)} < 10.1 V | - | 35 | - | dB | 5 |
| | | 1001 10111/1 | $10.1 \text{ V} \le V_{OUT(S)} \le 16.0 \text{ V}$ | _ | 30 | _ | dB | 5 |
| Short-circuit current | I _{short} | $V_{IN} = V_{OUT(S)} + 2.0 \text{ V},$ $V_{ON/OFF} = V_{IN}, V_{OUT} = 0 \text{ V}$ | | - | 120 | - | mA | 3 |
| Thermal shutdown detection temperature | T _{SD} | Junction temperature | | - | 165 | - | °C | _ |
| Thermal shutdown release temperature | T _{SR} | Junction temperature | | _ | 140 | _ | °C | _ |
| Discharge shunt resistance during power-off | R _{LOW} | V _{IN} = 18.0 V, V _{ON / OFF} = 0 V, V _{OUT} | = 2.0 V | - | 70 | - | kΩ | 6 |

^{*1.} V_{OUT(S)}: Set output voltage

 $V_{\text{OUT(E)}}$: Actual output voltage

This specification is guaranteed by design.

The output voltage when $V_{IN} = V_{OUT(S)} + 2.0 \text{ V}$, $I_{OUT} = 10 \text{ mA}$

^{*2.} The output current at which the output voltage becomes 95% of V_{OUT(E)} after gradually increasing the output current.

^{*3.} $V_{drop} = V_{IN1} - (V_{OUT3} \times 0.98)$

 V_{IN1} is the input voltage at which the output voltage becomes 98% of V_{OUT3} after gradually decreasing the input voltage. V_{OUT3} is the output voltage when $V_{\text{IN}} = V_{\text{OUT(S)}} + 2.0 \text{ V}$, and $I_{\text{OUT}} = 125 \text{ mA}$ or 250 mA.

^{*4.} Due to limitation of the power dissipation, this value may not be satisfied. Attention should be paid to the power dissipation when the output current is large.

■ Test Circuits

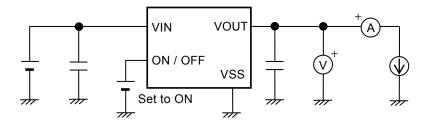


Figure 8 Test Circuit 1

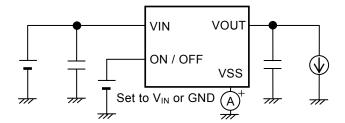


Figure 9 Test Circuit 2

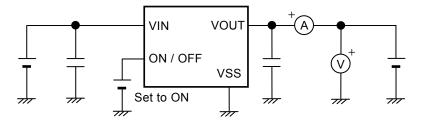


Figure 10 Test Circuit 3

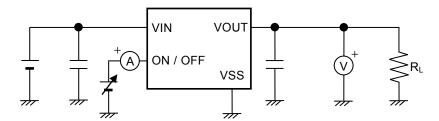


Figure 11 Test Circuit 4

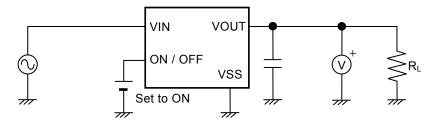


Figure 12 Test Circuit 5

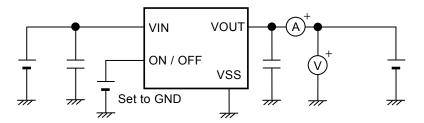
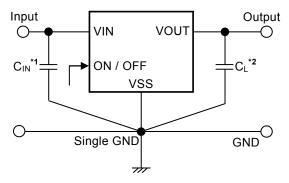


Figure 13 Test Circuit 6

■ Standard Circuit



- *1. C_{IN} is a capacitor for stabilizing the input.
- *2. C_L is a capacitor for stabilizing the output.

Figure 14

Caution The above connection diagram and constants will not guarantee successful operation. Perform thorough evaluation using an actual application to set the constants.

■ Condition of Application

Input capacitor (C_{IN}): A ceramic capacitor with capacitance of 1.0 μF or more is recommended. Output capacitor (C_L): A ceramic capacitor with capacitance of 1.0 μF to 100 μF is recommended.

Caution Generally, in a voltage regulator, an oscillation may occur depending on the selection of the external parts. Perform thorough evaluation including the temperature characteristics with an actual application using the above capacitors to confirm no oscillation occurs.

■ Selection of Input Capacitor (C_{IN}) and Output Capacitor (C_L)

The S-1212B/D Series requires C_L between the VOUT pin and the VSS pin for phase compensation. The operation is stabilized by a ceramic capacitor with capacitance of 1.0 μ F to 100 μ F. When using an OS capacitor, a tantalum capacitor or an aluminum electrolytic capacitor, the capacitance also must be 1.0 μ F to 100 μ F. However, an oscillation may occur depending on the equivalent series resistance (ESR).

Moreover, the S-1212B/D Series requires C_{IN} between the VIN pin and the VSS pin for a stable operation.

Generally, an oscillaiton may occur when a voltage regulator is used under the conditon that the impedance of the power supply is high.

Note that the output voltage transient characteristics varies depending on the capacitance of C_{IN} and C_L and the value of ESR.

Caution Perform thorough evaluation including the temperature characteristics with an actual application to select C_{IN} and C_L.

■ Explanation of Terms

1. Low dropout voltage regulator

This is a voltage regulator which made dropout voltage small by its built-in low on-resistance output transistor.

2. Output voltage (Vout)

This voltage is output at an accuracy of $\pm 2.0\%$ when the input voltage, the output current and the temperature are in a certain condition*1.

*1. Differs depending on the product.

Caution If the certain condition is not satisfied, the output voltage may exceed the accuracy range of ±2.0%. Refer to "■ Electrical Characteristics" and "■ Characteristics (Typical Data)" for details.

3. Line regulation
$$\left(\frac{\Delta V_{OUT1}}{\Delta V_{IN} \bullet V_{OUT}}\right)$$

Indicates the dependency of the output voltage against the input voltage. That is, the value shows how much the output voltage changes due to a change in the input voltage after fixing output current constant.

4. Load regulation (ΔV_{OUT2})

Indicates the dependency of the output voltage against the output current. That is, the value shows how much the output voltage changes due to a change in the output current after fixing input voltage constant.

5. Dropout voltage (V_{drop})

Indicates the difference between input voltage (V_{IN1}) and the output voltage when the output voltage becomes 98% of the output voltage value (V_{OUT3}) at $V_{IN} = V_{OUT(S)} + 2.0$ V after the input voltage (V_{IN}) is decreased gradually.

$$V_{drop} = V_{IN1} - (V_{OUT3} \times 0.98)$$

Operation

1. Basic operation

Figure 15 shows the block diagram of the S-1212B/D Series to describe the basic operation.

The error amplifier compares the feedback voltage (V_{fb}) whose output voltage (V_{OUT}) is divided by the feedback resistors $(R_s$ and $R_f)$ with the reference voltage (V_{ref}) . The error amplifier controls the output transistor, consequently, the regulator starts the operation that holds V_{OUT} constant without the influence of the input voltage (V_{IN}) .

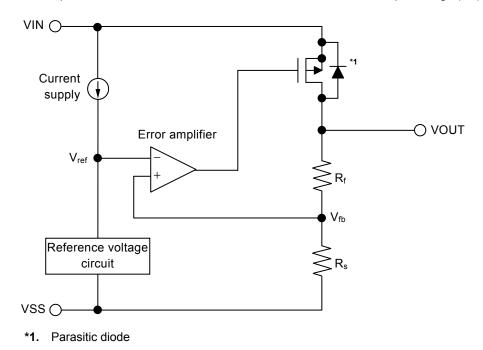


Figure 15

2. Output transistor

In the S-1212B/D Series, a low on-resistance P-channel MOS FET is used between the VIN pin and the VOUT pin as the output transistor. In order to hold V_{OUT} constant, the on-resistance of the output transistor varies appropriately according to the output current (I_{OUT}).

Caution Since a parasitic diode exists between the VIN pin and the VOUT pin due to the structure of the transistor, the IC may be damaged by a reverse current if V_{OUT} becomes higher than V_{IN} . Therefore, be sure that V_{OUT} does not exceed $V_{IN} + 0.3 \ V$.

3. ON / OFF pin

The ON / OFF pin controls the internal circuit and the output transistor in order to start and stop the regulator. When the ON / OFF pin is set to OFF, the internal circuit stops operating and the output transistor between the VIN pin and the VOUT pin is turned off, reducing current consumption significantly.

The internal equivalent circuit related to the ON / OFF pin is configured as shown in **Figure 16**. Since the ON / OFF pin is neither pulled down nor pulled up, do not use it in the floating status. When not using the ON / OFF pin, connect it to the VIN pin. Note that the current consumption increases when a voltage of V_{SL} max.*¹ to $V_{IN} - 0.3$ V is applied to the ON / OFF pin.

Table 14

| Product Type | ON / OFF Pin | Internal Circuit | VOUT Pin Voltage | Current Consumption |
|--------------|--------------|------------------|-----------------------------------|---------------------|
| B/D | "H": ON | Operate | Constant value*2 | I _{SS1} |
| B/D | "L": OFF | Stop | Pulled down to V _{SS} *3 | I _{SS2} |

^{*1.} Refer to Table 13 in "■ Electrical Characteristics".

^{*3.} The VOUT pin voltage is pulled down to V_{SS} due to the discharge shunt circuit (R_{LOW} = 70 k Ω typ.), the feedback resistors (R_s and R_f) and a load.

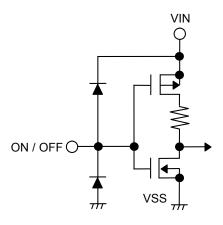


Figure 16

4. Overcurrent protection circuit

The S-1212B/D Series has a built-in overcurrent protection circuit to limit the overcurrent of the output transistor. When the VOUT pin is shorted with the VSS pin, that is, at the time of the output short-circuit, the output current is limited to 120 mA typ. due to the overcurrent protection circuit operation. The S-1212B/D Series restarts regulating when the output transistor is released from the overcurrent status.

- Caution 1. This overcurrent protection circuit does not work as for thermal protection. For example, when the output transistor keeps the overcurrent status long at the time of output short-circuit or due to other reasons, pay attention to the conditions of the input voltage and the load current so as not to exceed the power dissipation.
 - 2. Note that any interference may be caused in the output voltage start-up when a load heavier than $\frac{V_{\text{OUT(S)}}}{100~\text{mA}}$ is connected.

^{*2.} The constant value is output due to the regulating based on the set output voltage value.

5. Thermal shutdown circuit

The S-1212B/D Series has a built-in thermal shutdown circuit to limit overheating. When the junction temperature increases to 165°C typ., the thermal shutdown circuit becomes the detection status, and the regulating is stopped. When the junction temperature decreases to 140°C typ., the thermal shutdown circuit becomes the release status, and the regulator is restarted.

If the thermal shutdown circuit becomes the detection status due to self-heating, the regulating is stopped and V_{OUT} decreases. For this reason, the self-heating is limited and the temperature of the IC decreases. The thermal shutdown circuit becomes release status when the temperature of the IC decreases, and the regulating is restarted, thus the self-heating is generated again. Repeating this procedure makes the waveform of V_{OUT} into a pulse-like form. This phenomenon continues unless decreasing either or both of the input voltage and the output current in order to reduce the internal power consumption, or decreasing the ambient temperature. Note that the product may suffer physical damage such as deterioration if the above phenomenon occurs continuously.

- Caution 1. When the heat radiation of the application is not in a good condition, the self-heating cannot be limited immediately, and the IC may suffer physical damage. Perform thorough evaluation including the temperature characteristics with an actual application to confirm no problems happen.
 - 2. If a large load current flows during the restart process of regulating after the thermal shutdown circuit changes to the release status from the detection status, the thermal shutdown circuit becomes the detection status again due to self-heating, and a problem may happen in the restart of regulating. A large load current, for example, occurs when charging to the C_L whose capacitance is large.

Perform thorough evaluation including the temperature characteristics with an actual application to select C_L .

Table 15

| Thermal Shutdown Circuit | VOUT Pin Voltage |
|--------------------------|-----------------------------------|
| Release: 140°C typ.*1 | Constant value*2 |
| Detection: 165°C typ.*1 | Pulled down to V _{SS} *3 |

^{*1.} Junction temperature

^{*2.} The constant value is output due to the regulating based on the set output voltage value.

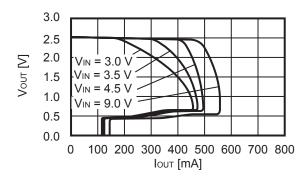
^{*3.} The VOUT pin voltage is pulled down to VSS due to the feedback resistors (Rs and Rf) and a load.

■ Precautions

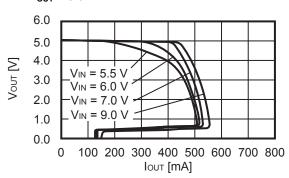
- Generally, when a voltage regulator is used under the condition that the load current value is small (0.1 mA or less), the output voltage may increase due to the leakage current of an output transistor.
- Generally, when a voltage regulator is used under the condition that the temperature is high, the output voltage may increase due to the leakage current of an output transistor.
- Generally, when the ON / OFF pin is used under the condition of OFF, the output voltage may increase due to the leakage current of an output transistor.
- Generally, when a voltage regulator is used under the condition that the impedance of the power supply is high, an oscillation may occur. Perform thorough evaluation including the temperature characteristics with an actual application to select C_{IN}.
- Generally, in a voltage regulator, an oscillation may occur depending on the selection of the external parts. The following use conditions are recommended in the S-1212B/D Series, however, perform thorough evaluation including the temperature characteristics with an actual application to select C_{IN} and C_L.
 - Input capacitor (C_{IN}): A ceramic capacitor with capacitance of 1.0 μF or more is recommended. Output capacitor (C_L): A ceramic capacitor with capacitance of 1.0 μF to 100 μF is recommended.
- Generally, in a voltage regulator, the values of an overshoot and an undershoot in the output voltage vary depending
 on the variation factors of input voltage start-up, input voltage fluctuation and load fluctuation etc., or the capacitance
 of C_{IN} or C_L and the value of the equivalent series resistance (ESR), which may cause a problem to the stable
 operation. Perform thorough evaluation including the temperature characteristics with an actual application to select
 C_{IN} and C_L.
- Generally, in a voltage regulator, an overshoot may occur in the output voltage momentarily if the input voltage steeply changes when the input voltage is started up or the input voltage fluctuates etc. Perform thorough evaluation including the temperature characteristics with an actual application to confirm no problems happen.
- Generally, in a voltage regulator, if the VOUT pin is steeply shorted with GND, a negative voltage exceeding the absolute maximum ratings may occur in the VOUT pin due to resonance phenomenon of the inductance and the capacitance including C_L on the application. The resonance phenomenon is expected to be weakened by inserting a series resistor into the resonance path, and the negative voltage is expected to be limited by inserting a protection diode between the VOUT pin and the VSS pin.
- If the input voltage is started up steeply under the condition that the capacitance of C_L is large, the thermal shutdown circuit may be in the detection status by self-heating due to the charge current to C_L.
- Make sure of the conditions for the input voltage, output voltage and the load current so that the internal loss does not exceed the power dissipation.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- When considering the output current value that the IC is able to output, make sure of the output current value specified in **Table 13** in **"■ Electrical Characteristics"** and footnote *4 of the table.
- Wiring patterns on the application related to the VIN pin, the VOUT pin and the VSS pin should be designed so that the impedance is low. When mounting C_{IN} between the VIN pin and the VSS pin and C_L between the VOUT pin and the VSS pin, connect the capacitors as close as possible to the respective destination pins of the IC.
- In the package equipped with heat sink of backside, mount the heat sink firmly. Since the heat radiation differs according to the condition of the application, perform thorough evaluation with an actual application to confirm no problems happen.
- SII Semiconductor Corporation claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

■ Characteristics (Typical Data)

- 1. Output voltage vs. Output current (When load current increases) (Ta = +25°C)
 - 1. 1 V_{OUT} = 2.5 V

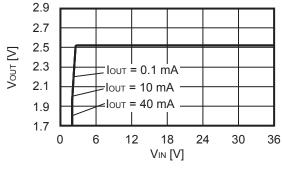


1. 2 V_{OUT} = 5.0 V

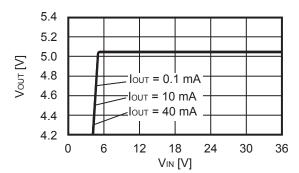


Remark In determining the output current, attention should be paid to the following.

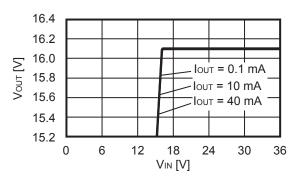
- 1. The minimum output current value and footnote *4 of Table 13 in "■ Electrical Characteristics"
- 2. Power dissipation
- 2. Output voltage vs. Input voltage (Ta = +25°C)
- 2. 1 $V_{OUT} = 2.5 V$



2. 2 V_{OUT} = 5.0 V

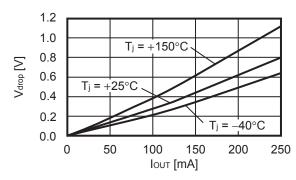


2. 3 $V_{OUT} = 16.0 V$

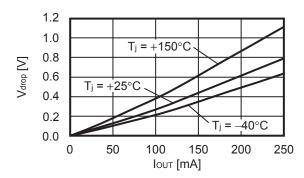


3. Dropout voltage vs. Output current

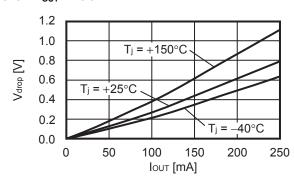
3. 1 $V_{OUT} = 2.5 V$



3. 2 V_{OUT} = 5.0 V

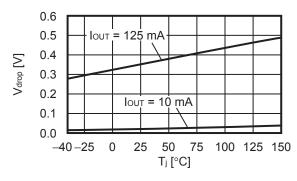


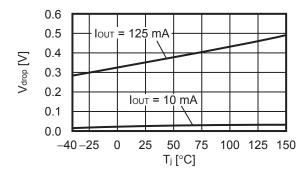
3. 3 V_{OUT} = 16.0 V



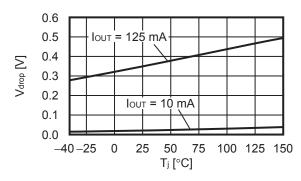
4. Dropout voltage vs. Junction temperature

4. 1 $V_{OUT} = 2.5 V$

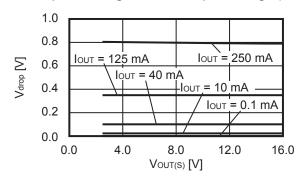




4. 3 $V_{OUT} = 16.0 V$

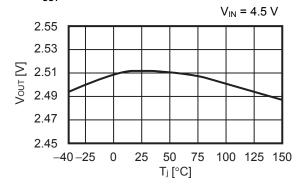


5. Dropout voltage vs. Set output voltage ($Ta = +25^{\circ}C$)

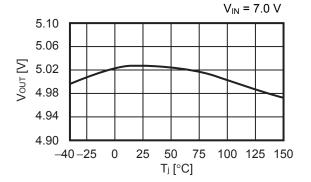


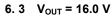
6. Output voltage vs. Junction temperature

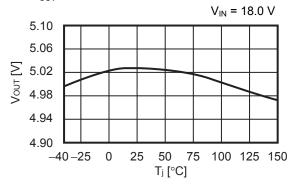
6. 1 $V_{OUT} = 2.5 V$



6. 2 V_{OUT} = 5.0 V

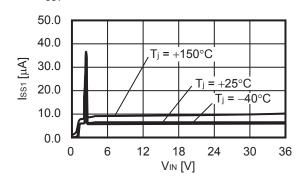


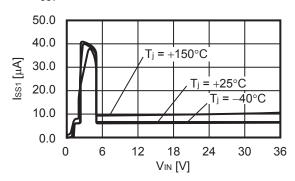




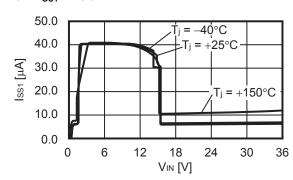
7. Current consumption during operation vs. Input voltage (When ON / OFF pin is ON, no load)

7. 1 $V_{OUT} = 2.5 V$



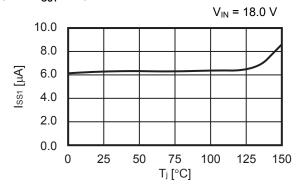


7. 3 V_{OUT} = 16.0 V

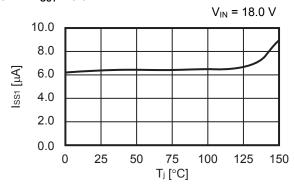


8. Current consumption during operation vs. Junction temperature

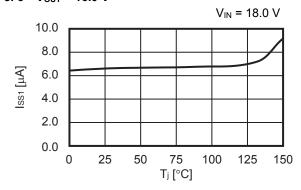
8. 1 $V_{OUT} = 2.5 V$



8. 2
$$V_{OUT} = 5.0 V$$

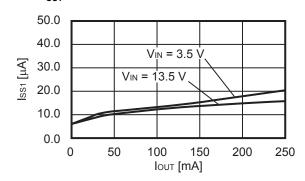


8. 3 V_{OUT} = 16.0 V

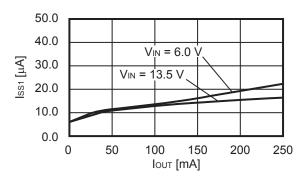


9. Current consumption during operation vs. Output current (Ta = +25°C)

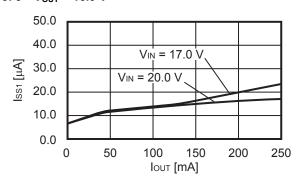
9. 1 V_{OUT} = 2.5 V



9. 2 V_{OUT} = 5.0 V

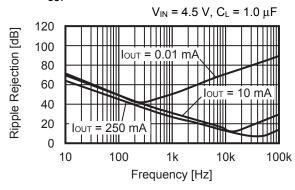


9. 3 V_{OUT} = 16.0 V

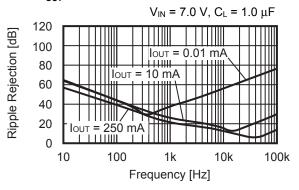


10. Ripple rejection (Ta = +25°C)

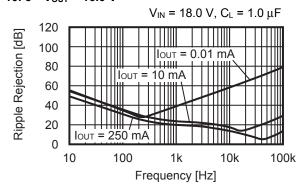
10. 1 V_{OUT} = 2.5 V



10. 2 V_{OUT} = 5.0 V



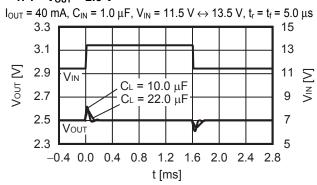
10. 3 V_{OUT} = 16.0 V



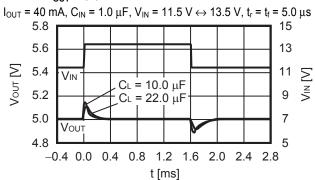
■ Reference Data

1. Characteristics of input transient response (Ta = +25°C)

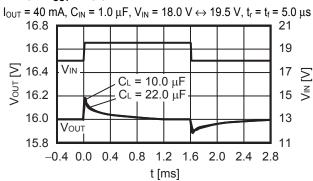
1. 1 $V_{OUT} = 2.5 V$



1. 2 $V_{OUT} = 5.0 V$

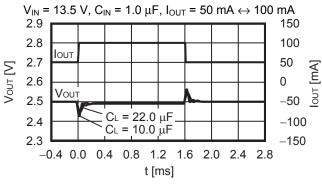


1. 3 V_{OUT} = 16.0 V

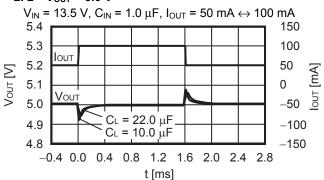


2. Characteristics of load transient response (Ta = +25°C)

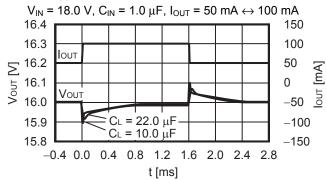
2. 1 V_{OUT} = 2.5 V



2. 2 $V_{OUT} = 5.0 V$

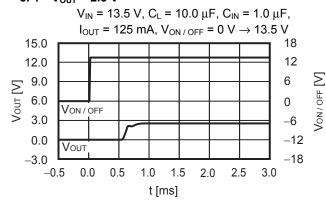


2. 3 $V_{OUT} = 16.0 V$

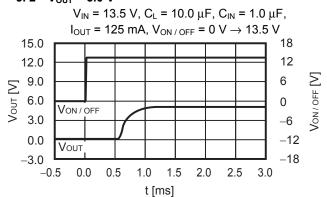


3. Transient response characteristics of ON / OFF pin (Ta = +25°C)

3. 1 V_{OUT} = 2.5 V

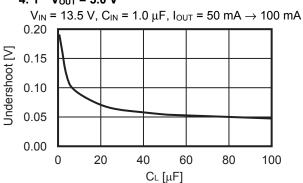


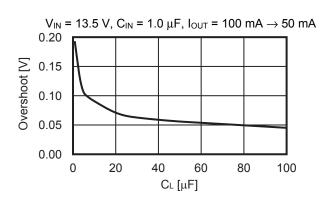
3. 2 Vout = 5.0 V



4. Load transient response characteristics dependent on capacitance (Ta = +25°C)

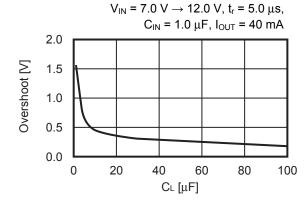
4. 1 V_{OUT} = 5.0 V

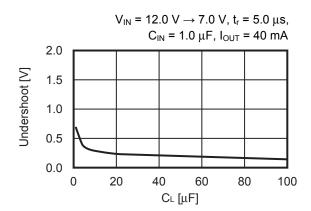




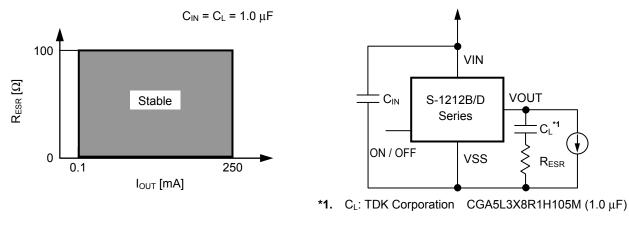
5. Input transient response characteristics dependent on capacitance ($Ta = +25^{\circ}C$)

5. 1 V_{OUT} = 5.0 V



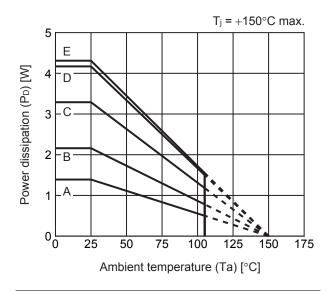


6. Example of equivalent series resistance vs. Output current characteristics (Ta = +25°C)

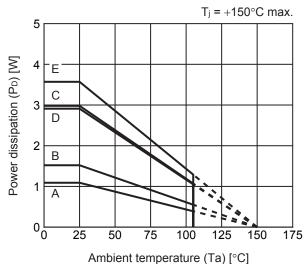


■ Power Dissipation

TO-252-5S(A)



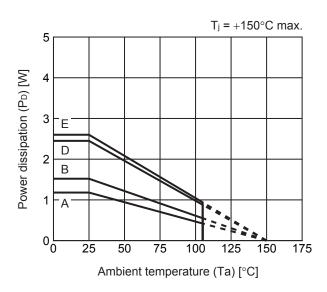
| HSOP-8A |
|---------|
| |



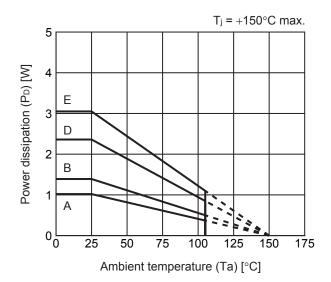
| Board | Power Dissipation (P _D) |
|-------|-------------------------------------|
| Α | 1.39 W |
| В | 2.16 W |
| С | 3.29 W |
| D | 4.17 W |
| Е | 4.31 W |

| Board | Power Dissipation (P _D) |
|-------|-------------------------------------|
| Α | 1.09 W |
| В | 1.52 W |
| С | 2.98 W |
| D | 2.91 W |
| Е | 3.57 W |

HSOP-6



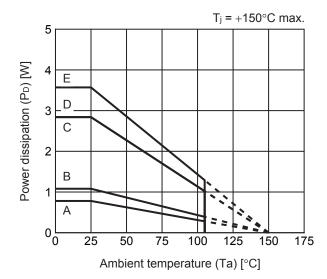
| SOT | -89-5 |
|-----|-------|
|-----|-------|



| Board | Power Dissipation (P _D) |
|-------|-------------------------------------|
| Α | 1.18 W |
| В | 1.52 W |
| С | _ |
| D | 2.45 W |
| Е | 2.60 W |

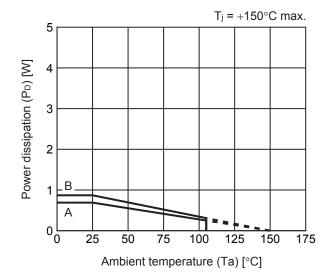
| Board | Power Dissipation (P _D) |
|-------|-------------------------------------|
| Α | 1.02 W |
| В | 1.39 W |
| С | _ |
| D | 2.36 W |
| Е | 3.05 W |

HTMSOP-8



| Board | Power Dissipation (P _D) |
|-------|-------------------------------------|
| Α | 0.78 W |
| В | 1.08 W |
| С | 2.84 W |
| D | 2.84 W |
| E | 3.57 W |

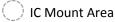
SOT-23-5

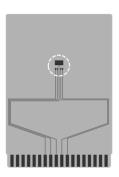


| Board | Power Dissipation (P _D) |
|-------|-------------------------------------|
| Α | 0.69 W |
| В | 0.87 W |
| С | _ |
| D | _ |
| F | _ |

TO-252-5S Test Board

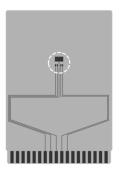
(1) Board A





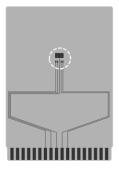
| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 2 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | - |
| | 3 | - |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(2) Board B



| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(3) Board C



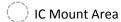
| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| | 1 | Land pattern and wiring for testing: t0.070 |
| Connor foil lover [mm] | 2 | 74.2 x 74.2 x t0.035 |
| Copper foil layer [mm] | 3 | 74.2 x 74.2 x t0.035 |
| 4 | | 74.2 x 74.2 x t0.070 |
| Thermal via | | Number: 4 Diameter: 0.3 mm |

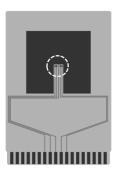


No. TO252-5S-A-Board-SD-1.0

TO-252-5S Test Board

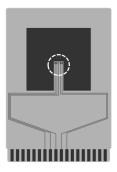
(4) Board D





| Item | | Specification |
|-----------------------------|---|--|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| | 1 | Pattern for heat radiation: 2000mm ² t0.070 |
| Coppor foil layer [mm] | 2 | 74.2 x 74.2 x t0.035 |
| Copper foil layer [mm] | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(5) Board E



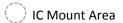
| Item | | Specification |
|-------------------------|------|--|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil I | ayer | 4 |
| Copper foil layer [mm] | 1 | Pattern for heat radiation: 2000mm ² t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| 4 | | 74.2 x 74.2 x t0.070 |
| Thermal via | | Number: 4 Diameter: 0.3 mm |



No. TO252-5S-A-Board-SD-1.0

HSOP-8A Test Board

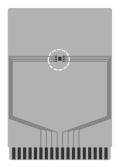
(1) Board A





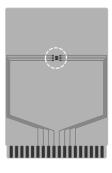
| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 2 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | - |
| | 3 | - |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(2) Board B



| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(3) Board C



| Item | | Specification |
|-------------------------|------|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil I | ayer | 4 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| Copper foil layer [min] | 3 | 74.2 x 74.2 x t0.035 |
| 4 | | 74.2 x 74.2 x t0.070 |
| Thermal via | | Number: 4 Diameter: 0.3 mm |

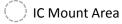


enlarged view

No. HSOP8A-A-Board-SD-1.0

HSOP-8A Test Board

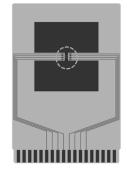
(4) Board D





| Item | | Specification |
|-----------------------------|---|--|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Pattern for heat radiation: 2000mm2 t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(5) Board E



| Item | | Specification |
|-----------------------------|---|--|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Pattern for heat radiation: 2000mm ² t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | Number: 4 Diameter: 0.3 mm |

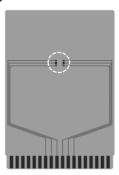


enlarged view

No. HSOP8A-A-Board-SD-1.0

HSOP-6 Test Board

(1) Board A



| Item | Sp | pecification |
|-----------------------------|----|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 2 |
| Copper foil layer [mm] 1 | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | - |
| | 3 | - |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

O IC Mount Area

(2) Board B



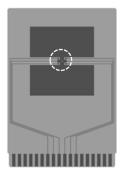
| Item Sp | | pecification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(3) Board D



| Item Sp | | pecification |
|-----------------------------|---|--|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Pattern for heat radiation: 2000mm ² t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(4) Board E



| Item | | Specification |
|-----------------------------|---|--|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| | 1 | Pattern for heat radiation: 2000mm ² t0.070 |
| Copper foil layer [mm] | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | Number: 4 |
| Themia via | | Diameter: 0.3 mm |

enlarged view

No. HSOP6-A-Board-SD-1.0

SOT-89-5 Test Board

(1) Board A



| | | O IC Mount Area | a |
|----|-------------|-----------------|---|
| Sp | ecification | | |
| | | | |

| Item | S | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 2 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | - |
| | 3 | - |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(2) Board B



| Item Sp | | pecification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(3) Board D



| Item | S | pecification |
|-----------------------------|---|--|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Pattern for heat radiation: 2000mm ² t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(4) Board E



| Item Sp | | Specification |
|-----------------------------|---|--|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Pattern for heat radiation: 2000mm ² t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | Number: 4 Diameter: 0.3 mm |



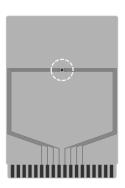
enlarged view

No. SOT895-A-Board-SD-1.0

HTMSOP-8/HMSOP-8 Test Board

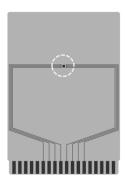
(1) Board A





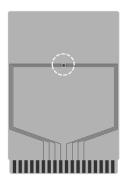
| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 2 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | - |
| | 3 | - |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(2) Board B



| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(3) Board C



| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | Number: 4 Diameter: 0.3 mm |

No. HTMSOP8/HMSOP8-A-Board-SD-1.0

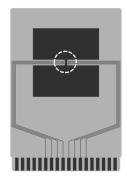


enlarged view

HTMSOP-8/HMSOP-8 Test Board

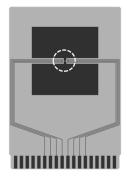
O IC Mount Area

(4) Board D



| Item | | Specification |
|-----------------------------|---|--|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Pattern for heat radiation: 2000mm ² t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(5) Board E



| Item | | Specification |
|-----------------------------|---|--|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Pattern for heat radiation: 2000mm ² t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | Number: 4 Diameter: 0.3 mm |

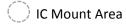


enlarged view

No. HTMSOP8/HMSOP8-A-Board-SD-1.0

SOT-23-3/5/6 Test Board

(1) Board A





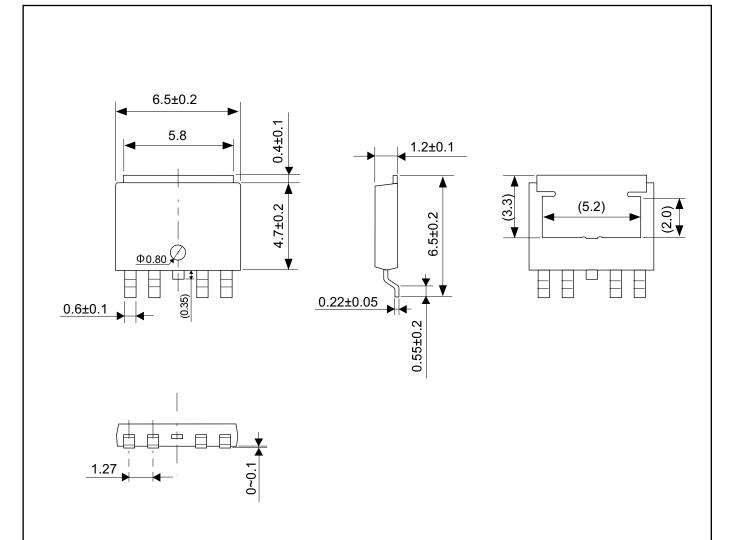
| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 2 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | - |
| | 3 | - |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(2) Board B



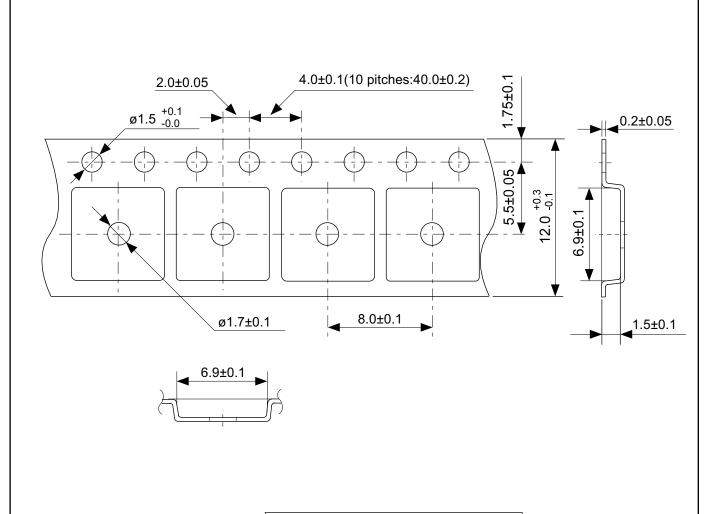
| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

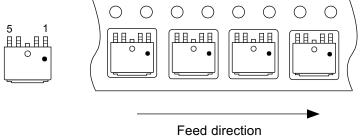
No. SOT23x-A-Board-SD-1.0



No. VA005-A-P-SD-2.0

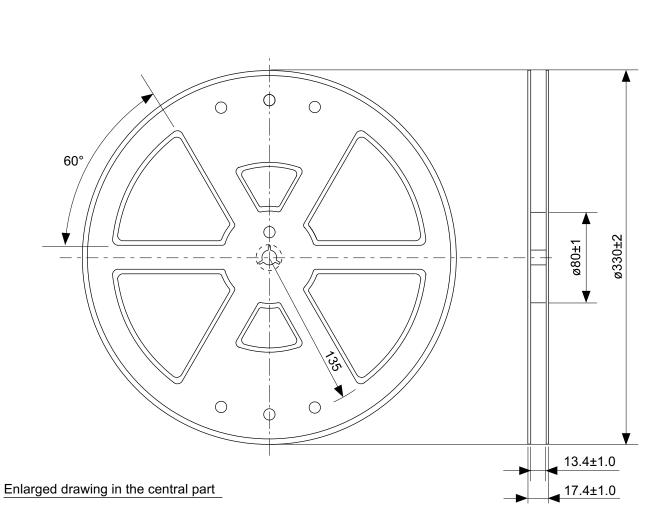
| TITLE | TO-252-5S-A-PKG Dimensions | |
|-----------------------------|------------------------------|--|
| No. | VA005-A-P-SD-2.0 | |
| ANGLE | \oplus | |
| UNIT | mm | |
| | | |
| SII S | emiconductor Corporation | |
| on commendation corporation | | |

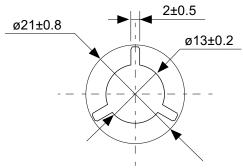




No. VA005-A-C-SD-1.0

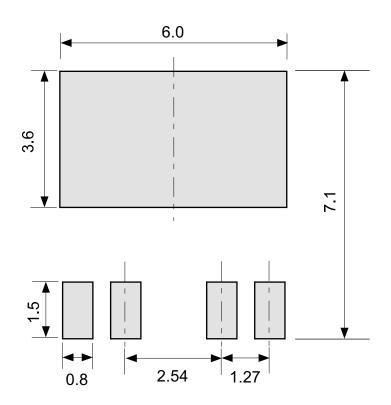
| TITLE | TO-252-5S-A-Carrier Tape | | |
|--------|-------------------------------|--|--|
| No. | VA005-A-C-SD-1.0 | | |
| ANGLE | | | |
| UNIT | mm | | |
| | | | |
| SII Se | SII Semiconductor Corporation | | |





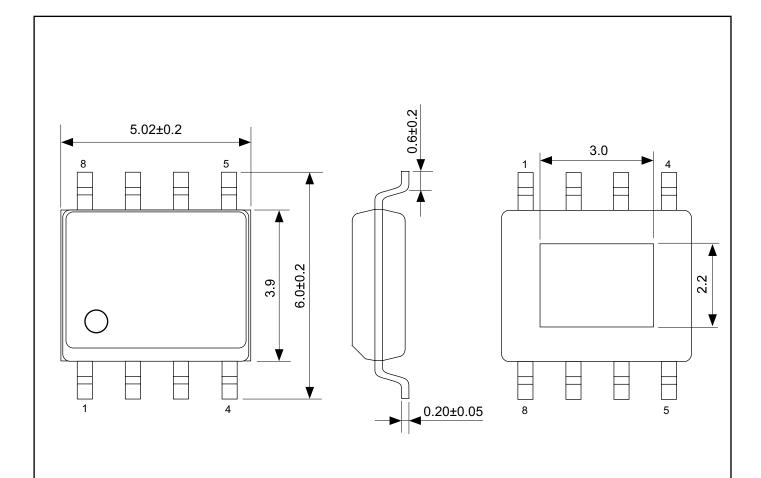
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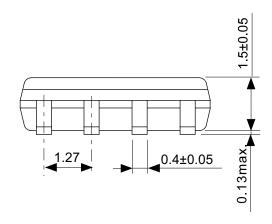
| TITLE | TO-252-5S-A-Reel | | |
|-------------------------------|------------------|------|-------|
| No. | VA005-A-R-SD-1.0 | | |
| ANGLE | | QTY. | 4,000 |
| UNIT | mm | | |
| | | | |
| SII Semiconductor Corporation | | | |



No. VA005-A-L-SD-1.0

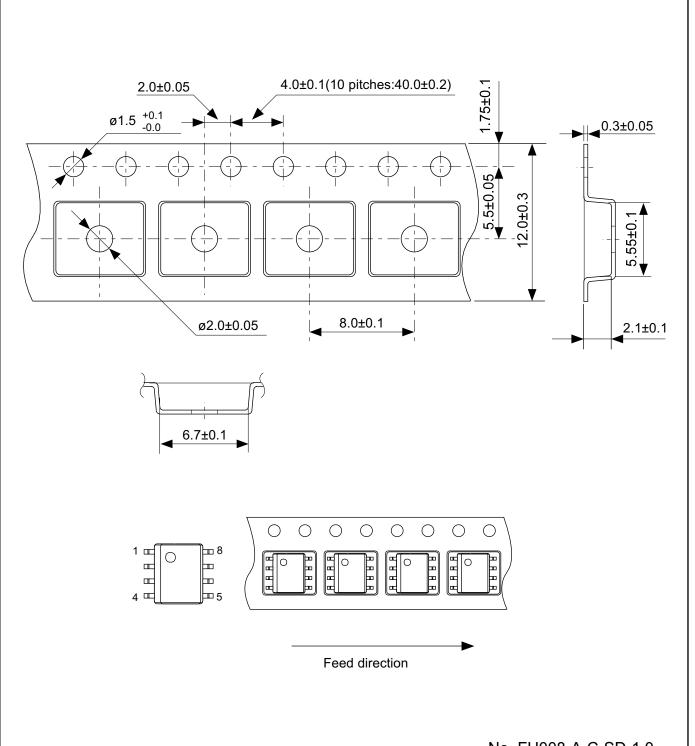
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|--------|-------------------------------------|--|
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| ANGLE | | |
| UNIT | mm | |
| | | |
| SII Se | emiconductor Corporation | |





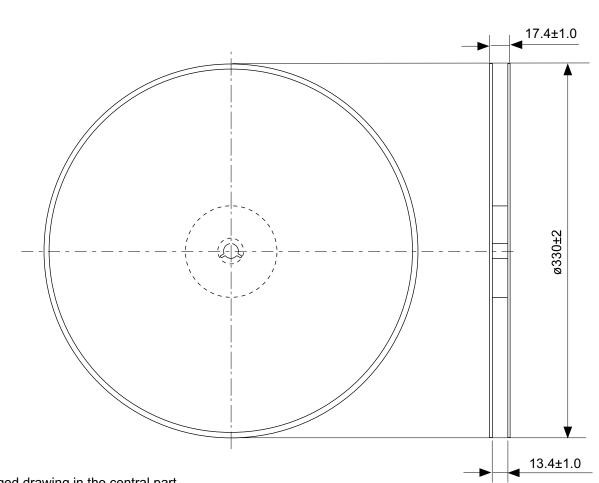
No. FH008-A-P-SD-2.0

| TITLE | HSOP8A-A-PKG Dimensions | |
|-------------------------------|-------------------------|--|
| No. | FH008-A-P-SD-2.0 | |
| ANGLE | ♦ € | |
| UNIT | mm | |
| | | |
| | | |
| | | |
| SII Semiconductor Corporation | | |

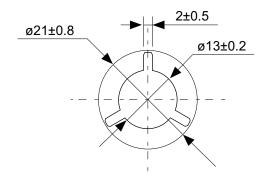


No. FH008-A-C-SD-1.0

| TITLE | HSOP8A-A-Carrier Tape | |
|-------------------------------|-----------------------|--|
| No. | FH008-A-C-SD-1.0 | |
| ANGLE | | |
| UNIT | mm | |
| | | |
| | | |
| | | |
| SII Semiconductor Corporation | | |
| No. ANGLE UNIT | FH008-A-C-SD-1.0 | |

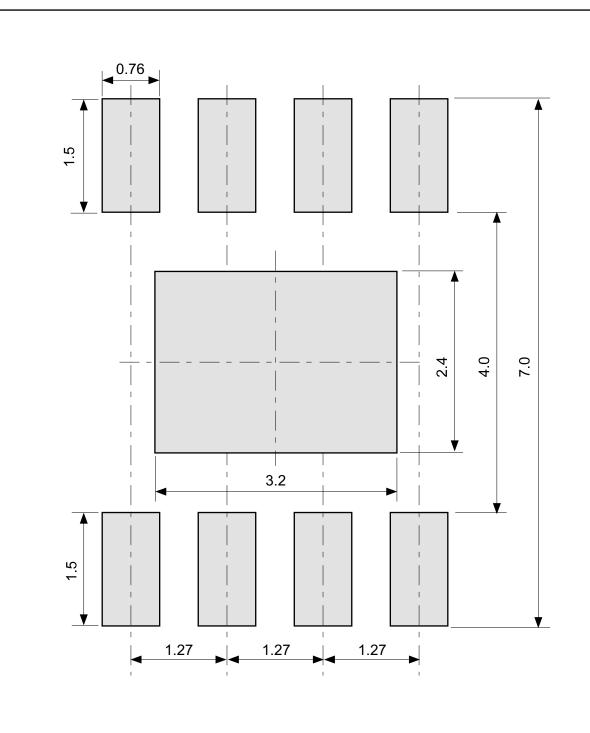


Enlarged drawing in the central part



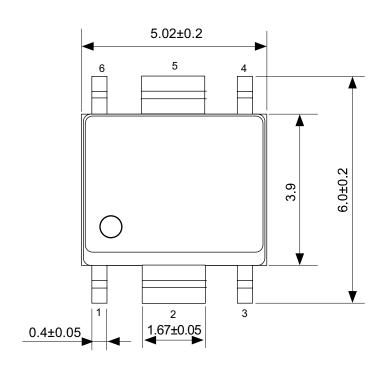
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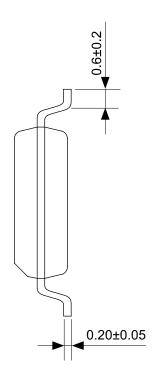
| TITLE | HSOF | 98A-A-R | eel |
|-------------------------------|------------------|---------|-------|
| No. | FH008-A-R-SD-1.0 | | |
| ANGLE | | QTY. | 4,000 |
| UNIT | mm | | |
| | | | |
| | | | |
| | | | |
| SII Semiconductor Corporation | | | |

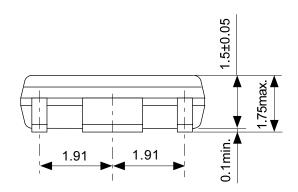


No. FH008-A-L-SD-1.0

| TITLE | HSOP8A-A -Land Recommendation | | |
|-------|----------------------------------|--|--|
| No. | FH008-A-L-SD-1.0 | | |
| ANGLE | | | |
| UNIT | mm | | |
| | | | |
| SII S | SII Semiconductor Corporation | | |

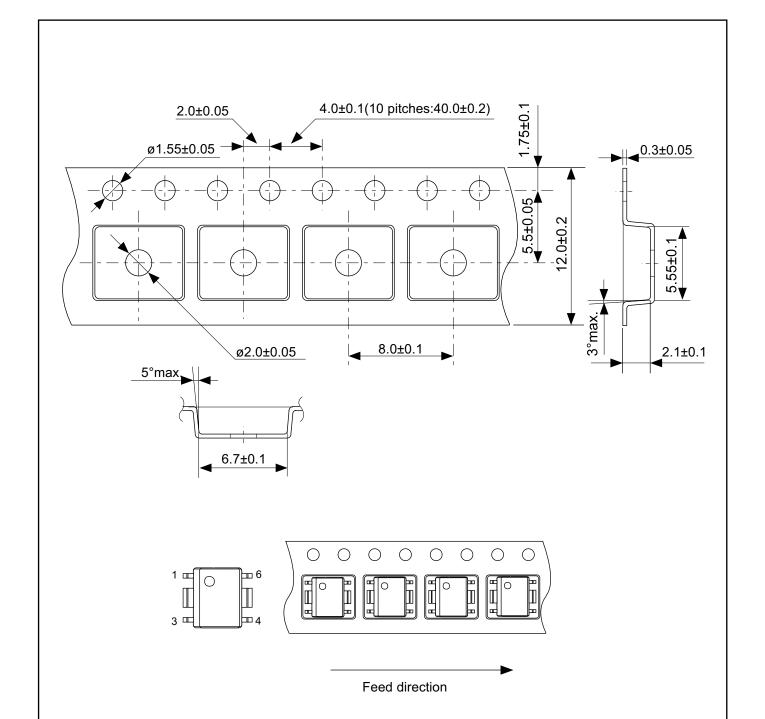






No. FH006-A-P-SD-2.1

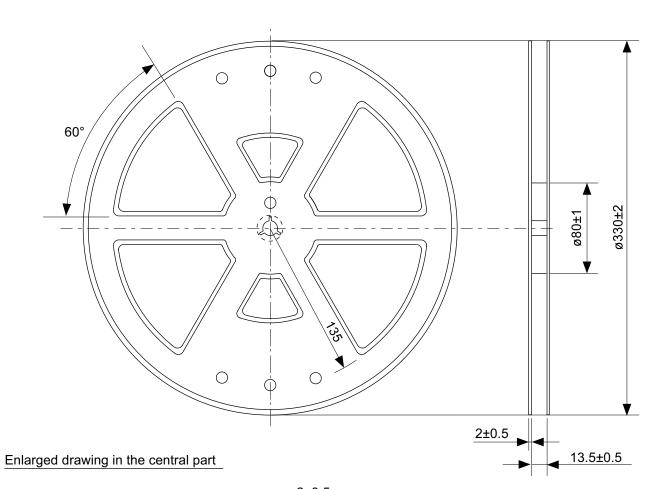
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|-------------------------------|------------------------|--|
| No. | FH006-A-P-SD-2.1 | |
| ANGLE | \$ | |
| UNIT | mm | |
| | | |
| | | |
| | | |
| | | |
| SII Semiconductor Corporation | | |

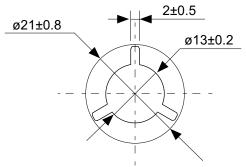


No. FH006-A-C-SD-1.0

| TITLE | HSOP6-A-Carrier Tape | |
|-------------------------------|----------------------|--|
| No. | FH006-A-C-SD-1.0 | |
| ANGLE | | |
| UNIT | mm | |
| | | |
| | | |
| | | |
| SII Semiconductor Corporation | | |

SII Semiconductor Corporation

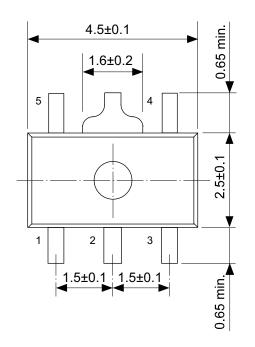


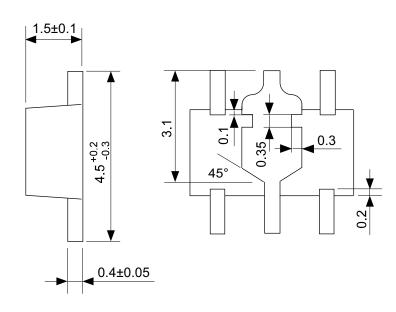


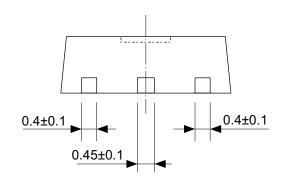
No. FH006-A-R-S1-1.0

| TITLE | HSOP6-A-Reel | | |
|-------------------------------|------------------|------|-------|
| No. | FH006-A-R-S1-1.0 | | |
| ANGLE | | QTY. | 4,000 |
| UNIT | mm | - | |
| | | | |
| | | | |
| | | | |
| SII Somiconductor Corneration | | | |

SII Semiconductor Corporation

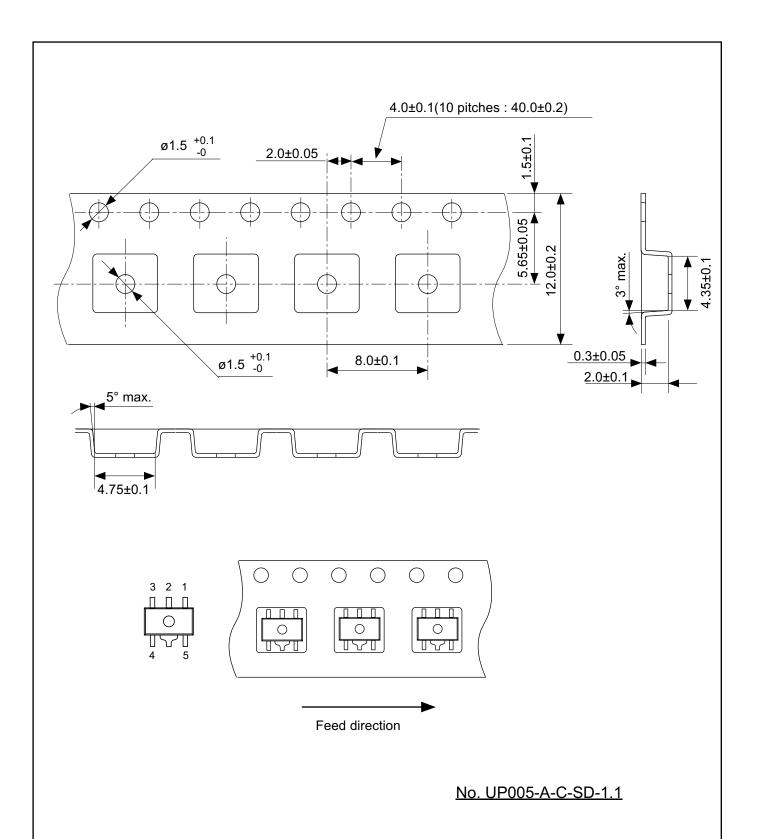




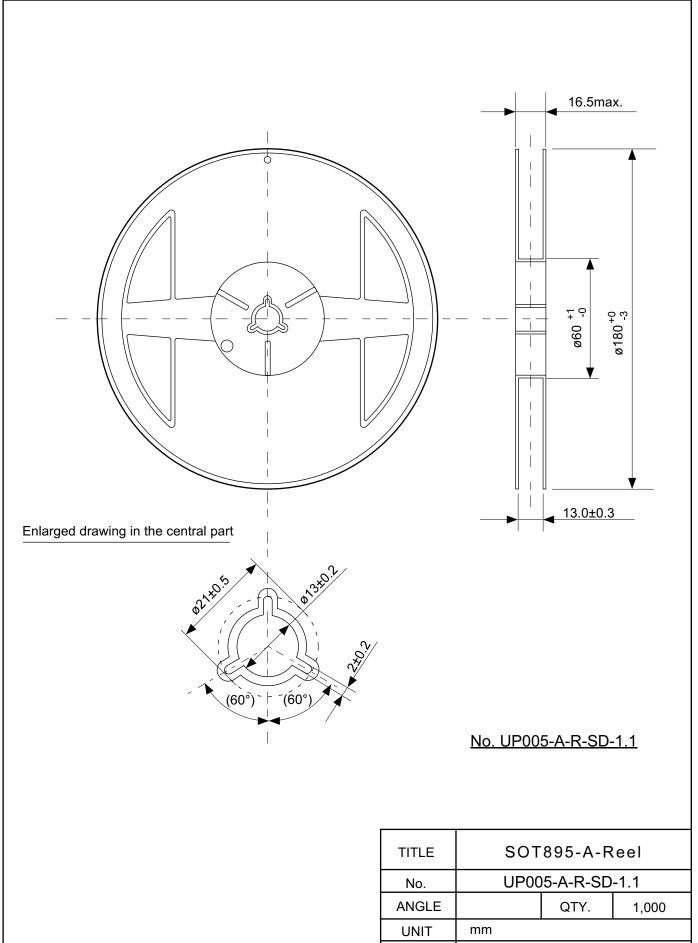


No. UP005-A-P-SD-2.0

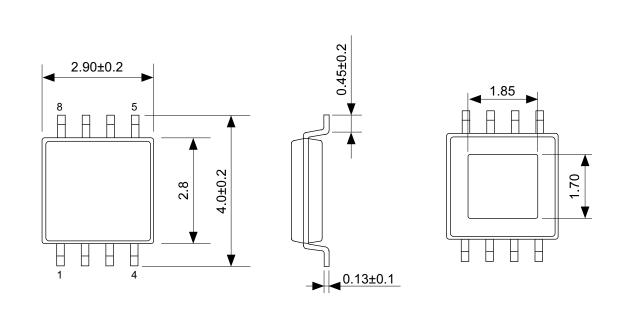
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|-------------------------------|-------------------------|--|
| No. | UP005-A-P-SD-2.0 | |
| ANGLE | \Pi | |
| UNIT | mm | |
| | | |
| | | |
| | | |
| SII Semiconductor Corporation | | |

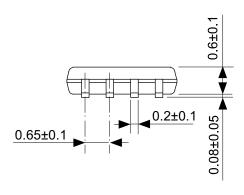


| TITLE | SOT895-A-Carrier Tape | | |
|-------------------------------|-----------------------|--|--|
| No. | UP005-A-C-SD-1.1 | | |
| ANGLE | | | |
| UNIT | mm | | |
| | | | |
| | | | |
| | | | |
| SII Semiconductor Corporation | | | |



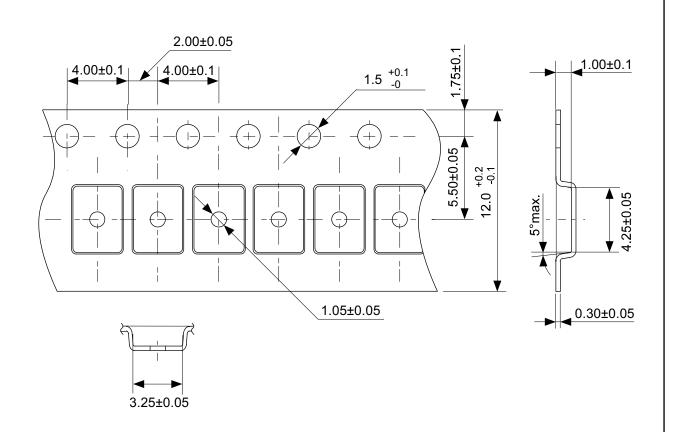
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|-------------------------------|------------------|------|-------|
| No. | UP005-A-R-SD-1.1 | | |
| ANGLE | | QTY. | 1,000 |
| UNIT | mm | | |
| | | | |
| | | | |
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| SII Semiconductor Corporation | | | |

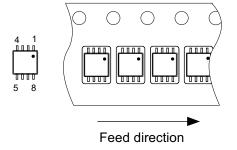




No. FP008-A-P-SD-2.0

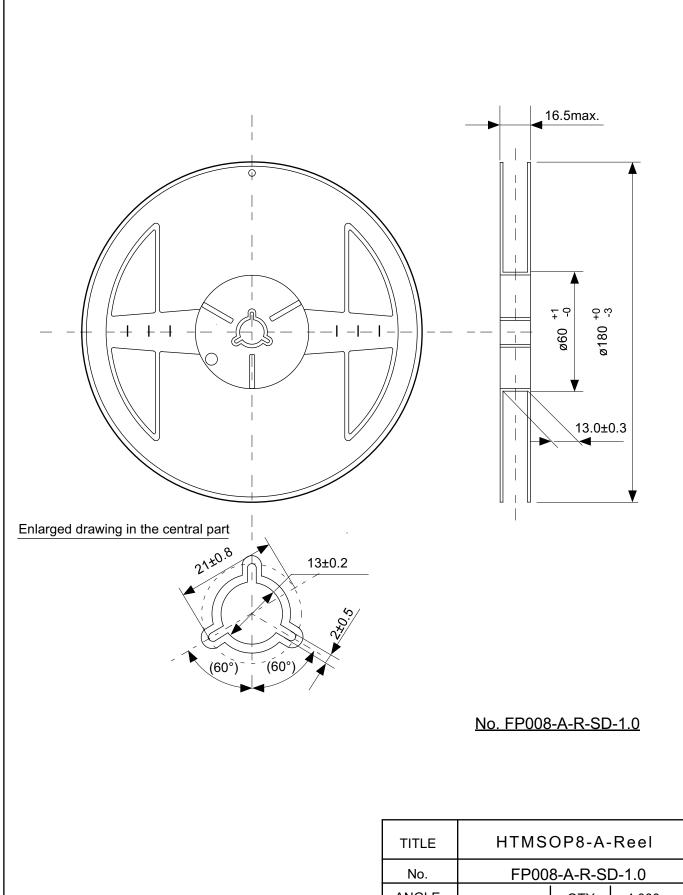
| TITLE | HTMSOP8-A-PKG Dimensions | | |
|-------------------------------|--------------------------|--|--|
| No. | FP008-A-P-SD-2.0 | | |
| ANGLE | \bigoplus | | |
| UNIT | mm | | |
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| SII Semiconductor Corporation | | | |



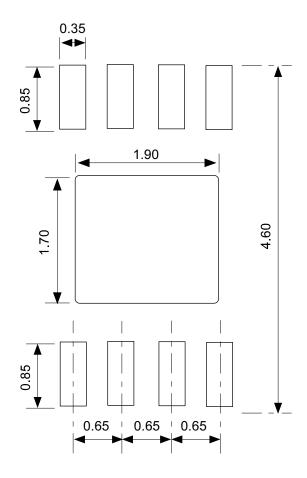


No. FP008-A-C-SD-1.0

| TITLE | HTMSOP8-A-Carrier Tape | | HTMSOP8-A-Carrier Tape | |
|-------------------------------|------------------------|--|------------------------|--|
| No. | FP008-A-C-SD-1.0 | | | |
| ANGLE | | | | |
| UNIT | mm | | | |
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| SII Semiconductor Corporation | | | | |

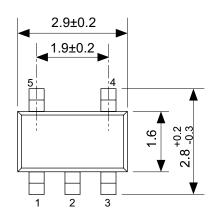


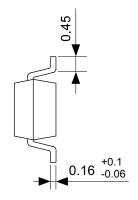
| ANGLE | | QTY. | 4,000 |
|-------------------------------|----|------|-------|
| UNIT | mm | • | |
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| SII Semiconductor Corporation | | | |
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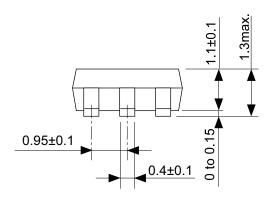


No. FP008-A-L-SD-2.0

| TITLE | HTMSOP8-A -Land Recommendation | |
|-------------------------------|-----------------------------------|--|
| No. | FP008-A-L-SD-2.0 | |
| ANGLE | | |
| UNIT | mm | |
| | | |
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| SII Semiconductor Corporation | | |

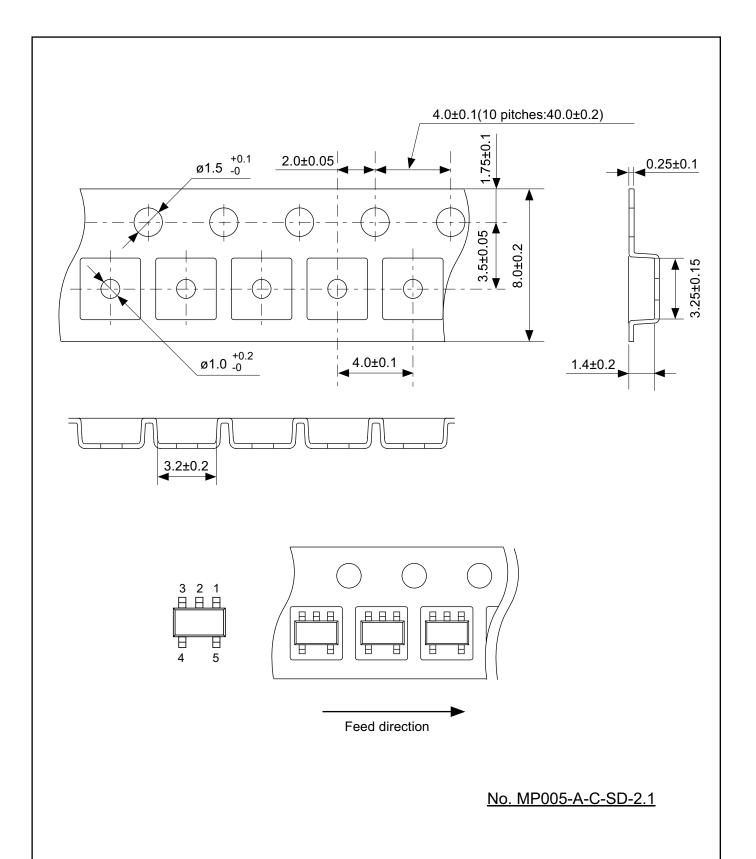




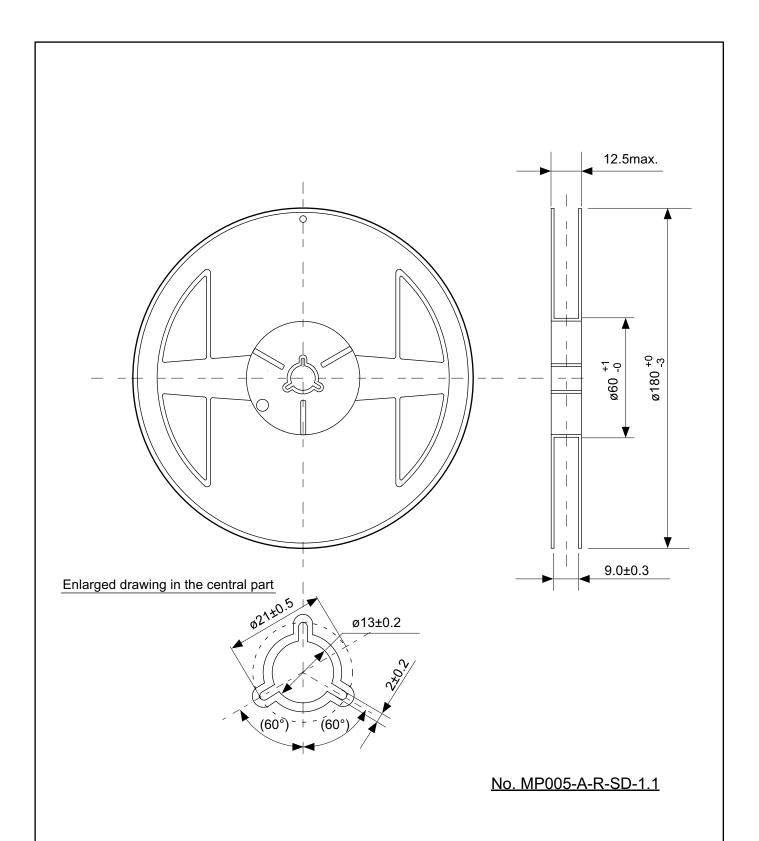


No. MP005-A-P-SD-1.3

| TITLE | SOT235-A-PKG Dimensions | | |
|-------|-------------------------------|--|--|
| No. | MP005-A-P-SD-1.3 | | |
| ANGLE | \$ = | | |
| UNIT | mm | | |
| | | | |
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| SILS | SII Semiconductor Corporation | | |



| TITLE | SOT235-A-Carrier Tape | |
|-------------------------------|-----------------------|--|
| No. | MP005-A-C-SD-2.1 | |
| ANGLE | | |
| UNIT | mm | |
| | | |
| | | |
| | | |
| SII Semiconductor Corporation | | |



| TITLE | SOT235-A-Reel | | |
|-------------------------------|------------------|------|-------|
| No. | MP005-A-R-SD-1.1 | | |
| ANGLE | | QTY. | 3,000 |
| UNIT | mm | | |
| | | | |
| | | | |
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| SII Semiconductor Corporation | | | |

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